High Directivity

Monolithic Amplifier 0.5-2.5 GHz

Product Features

- 2.8V & 5V operation
- Micro-miniature size .120”X.120”
- Internal DC blocking at RF input and output
- High directivity, 17 dB typ.
- Low noise figure
- Output power, up to +12.2 dBm typ.
- Excellent repeatability
- Low cost
- Aqueous washable

MNA-5+

CASE STYLE: DQ849
PRICE: $1.60 ea. QTY. (30)

+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

Typical Applications

- Buffer amplifier
- Cellular
- PCN
- Communications satellite
- Defense

General Description

MNA-5+ is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a 3x3 mm MCLP plastic package. MNA-5+ is fabricated using GaAs MESFET technology. Expected MTBF at 85°C case temperature is 120,000 years at 2.8V; 60,000 years at 5V.

Function	Pin Number	Description	
RF IN	2	RF input pin	
RF-OUT	5	RF output pin	
DC	7, with 1000 pF bypass to ground; connect pin 8 via 33 ohms to pin 7 externally		Bias pins
GND	3,4 and paddle in center of bottom		Connections to ground
OPTIONAL	1,6	No internal connection; recommended use: per PCB Layout PL-078	

Electrical Specifications at 25°C

Parameter		Min.	Typ.		Max.	Units
Frequency Range		0.5			2.5	GHz
at DC Volts		5.0	5.0	2.8	5.0	V
Gain	f=0.5 GHz		18.5	18.0		dB
	f=1.0 GHz		22.8	21.4		
	f=1.5 GHz		21.9	20.5		
	f=2.0 GHz	17.0	20.6	19.4		
	f=2.5 GHz		18.0	17.4		
Input Return Loss	f=0.75-2.5 GHz		12.5	12.5		dB
Output Return Loss	f=0.75-2.5 GHz		10	10		dB
Output Power @ 1 dB compression	f=0.5 GHz		12.2	10.1		dBm
	f=2.5GHz		8.0	6.5		
Output IP3	f=1 GHz		19.4	18.0		dBm
	f=2 GHz		21.0	20.0		
Noise Figure	f=1 GHz		3.5			dB
Directivity (Isolation - Gain)			17			
DC Current			28	26	40	mA
Thermal Resistance, junction-to-case			78			°C/W

Absolute Maximum Ratings

Parameter	Ratings
Operating Temperature	-40°C to 85°C
Storage Temperature	-55°C to 100°C
DC Voltage	7V at pin 7 10V at pins 2 & 5
Power Dissipation	500mW

Note: Permanent damage may occur if any of these limits are exceeded.
These ratings are not intended for continuous normal operation.

Product Marking

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: DQ849

MNA-5+: Plastic package, exposed paddle, lead finish: tin/silver/nickel

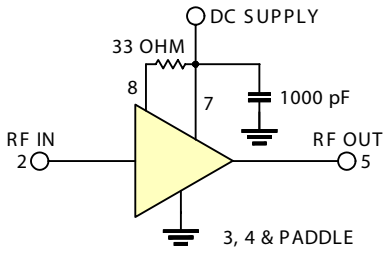
Tape & Reel: F66

Suggested Layout for PCB Design: PL-078

Evaluation Board: TB-186+

Environmental Ratings: ENV08T1

Recommended Application Circuit



ESD Rating

Human Body Model (HBM): Class 1A (250v to < 500v) in accordance with ANSI/ESD STM 5.1 - 2001

Charged Device Model (CDM): Class III (500 to 1000v) in accordance with JESD22-C101A

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL Test Flow Chart